

Notice of References Cited

Application/Control No.

09/652,998

Applicant(s)/Patent Under
Reexamination
DURCAN ET AL.

Examiner

Anh D. Mai

Art Unit

2814

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*		Document Number	Date	Name	Classification	
		Country Code-Number-Kind Code	MM-YYYY			
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	B	US-				
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	D	US-				
	E	US-				
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	I	US-				
	J	US-				
	K	US-				
	L	US-				
	M	US-				

FOREIGN PATENT DOCUMENTS

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NON-PATENT DOCUMENTS

*		Include as applicable: Author, Title Date, Publisher, Edition or Volume, Pertinent Pages)
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*A copy of this reference is not being furnished with this Office action. (See MPEP § 707.05(a).)

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